

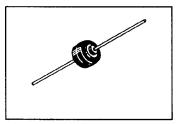
- Current Capacity Comparable to Chassis Mounted Rectifiers
- · Very High Surge Capacity
- Insulated Case

### Mechanical Characteristics:

- · Case: Epoxy, Molded
- Weight: 2.5 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Lead is Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Polarity: Cathode Polarity Band

MR750 MR751 MR752 MR754 MR756 MR758 MR760

HIGH CURRENT LEAD MOUNTED SILICON RECTIFIERS 50–1000 VOLTS DIFFUSED JUNCTION



### **MAXIMUM RATINGS**

Characteristic	Symbol	MR750	MR751	MR752	MR754	MR756	MR758	MR760	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>R</sub> WM V <sub>R</sub>	50	100	200	400	600	800	1000	Volts
Non-Repetitive Peak Reverse Voltage (Halfwave, single phase, 60 Hz peak)	V <sub>RSM</sub>	60	120	240	480	720	960	1200	Volts
RMS Reverse Voltage	V <sub>R</sub> (RMS)	35	70	140	280	420	560	700	Volts
Average Rectified Forward Current (Single phase, resistive load, 60 Hz) See Figures 5 and 6	10	22 (T <sub>L</sub> = 60°C, 1/8 Lead Lengths) 6.0 (T <sub>A</sub> = 60°C, P.C. Board mounting)							Amps
Non-Repetitive Peak Surge Current (Surge applied at rated load conditions)	<sup>1</sup> FSM	400 (for 1 cycle)							Amps
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +175						°C	

## **ELECTRICAL CHARACTERISTICS**

Characteristic and Conditions	Symbol	Max	Unit	
Maximum Instantaneous Forward Voltage Drop (i <sub>F</sub> = 100 Amps, T <sub>J</sub> = 25°C)	٧F	1.25	Volts	
Maximum Forward Voltage Drop (IF = 6.0 Amps, T <sub>A</sub> = 25°C, 3/8 leads)	VF	0.90	Volts	
	<sup>I</sup> R	25 1.0	μA mA	

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### PACKAGE DIMENSIONS

